

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1145

Audio Frequency Amplifier Applications

Unit: mm

- Complementary to 2SC2705.
- Small Collector Output Capacitance: Cob = 2.5 pF (typ.)
- High Transition Frequency: fT = 200 MHz (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-150	V	
Collector-emitter voltage	V _{CEO}	-150	V	
Emitter-base voltage	V _{EBO}	-5	V	
Collector current	IC	-50	mA	
Base current	IB	-5	mA	
Collector power dissipation	PC	800	mW	
Junction temperature	N . O 7;5	150	°C	
Storage temperature range	T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

Weight: 0.36 g (typ.)

TO-92MOD

2-5J1A

1.0MAX

0.6MAX

EMITTER
 COLLECTOR
 BASE

JEDEC

JEITA

TOSHIBA

operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



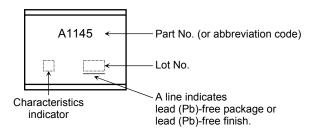


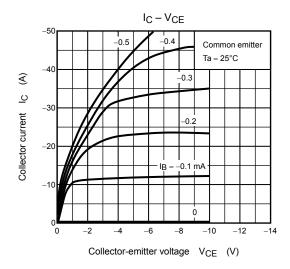
Electrical Characteristics (Ta = 25°C)

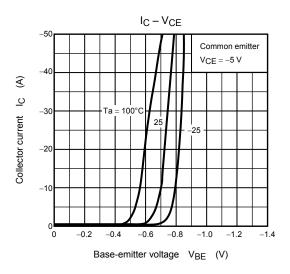
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -150 \text{ V}, I_E = 0$	_	_	-0.1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-0.1	μА
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -1 \text{ mA}, I_B = 0$	-150	_	_	V
DC current gain	h _{FE} (Note)	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	80	_	240	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$	_	_	-1.0	V
Base-emitter voltage	V_{BE}	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	_	_	-0.8	V
Transition frequency	f _T	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	_	200	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	2.5	_	pF

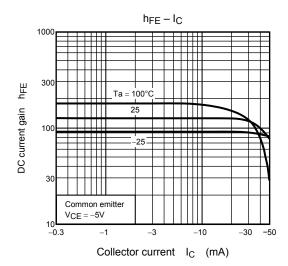
Note: hFE classification O: 80 to 160, Y: 120 to 240

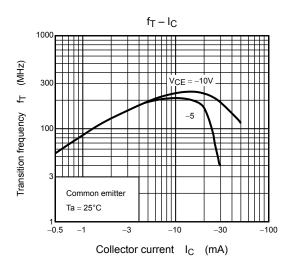
Marking

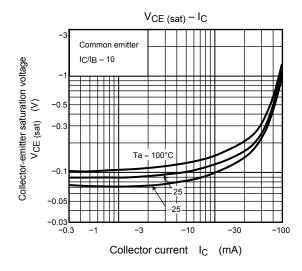


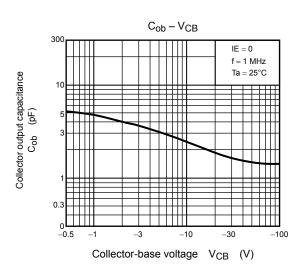


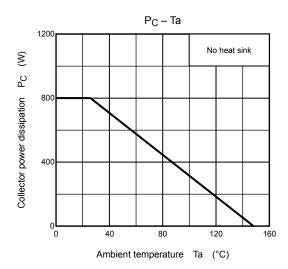












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